

October 2014

## **FDMS7572S**

# N-Channel PowerTrench<sup>®</sup> SyncFET<sup>TM</sup> 25 V, 49 A, 2.9 m $\Omega$

### **Features**

- Max  $r_{DS(on)}$  = 2.9 m $\Omega$  at  $V_{GS}$  = 10 V,  $I_D$  = 23 A
- $\blacksquare$  Max  $\rm r_{DS(on)}$  = 4.2 m $\Omega$  at  $\rm V_{GS}$  = 4.5 V,  $\rm I_D$  = 18 A
- $\blacksquare$  Advanced Package and Silicon combination for low  $r_{\text{DS}(\text{on})}$  and high efficiency
- SyncFET Schottky Body Diode
- MSL1 robust package design
- 100% UIL tested
- RoHS Compliant

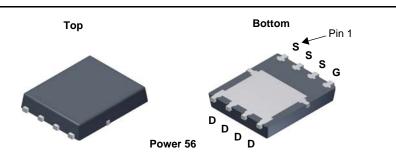


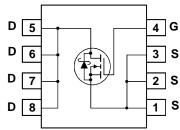
### **General Description**

The FDMS7572S has been designed to minimize losses in power conversion application. Advancements in both silicon and package technologies have been combined to offer the lowest  $r_{\text{DS}(\text{on})}$  while maintaining excellent switching performance. This device has the added benefit of an efficient monolithic Schottky body diode.

### **Applications**

- Synchronous Rectifier for Synchronous Buck Converters
- Notebook
- Server
- Telecom
- High Efficiency DC-DC Switch Mode Power Supplies





## MOSFET Maximum Ratings T<sub>A</sub> = 25 °C unless otherwise noted

Symbol	Parameter		Ratings	Units		
V <sub>DS</sub>	Drain to Source Voltage			25	V	
$V_{GS}$	Gate to Source Voltage		(Note 4)	±20	V	
	Drain Current -Continuous (Package limited)	T <sub>C</sub> = 25 °C		49		
	-Continuous (Silicon limited)	T <sub>C</sub> = 25 °C		105	^	
<sup>I</sup> D	-Continuous	T <sub>A</sub> = 25 °C	(Note 1a)	23	A	
	-Pulsed			150		
E <sub>AS</sub>	Single Pulse Avalanche Energy (No		(Note 3)	84	mJ	
Б	Power Dissipation	T <sub>C</sub> = 25 °C		46	W	
$P_{D}$	Power Dissipation $T_A = 25 ^{\circ}\text{C}$ (Note 1a)		(Note 1a)	2.5	VV	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range			-55 to +150	°C	

### **Thermal Characteristics**

$R_{\theta J}$	Thermal Resistance, Junction to Case	2.3	°C/M
$R_{\theta,I}$	Thermal Resistance, Junction to Ambient (No.	ote 1a) 50	°C/W

### **Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS7572S	FDMS7572S	Power 56	13 "	12 mm	3000 units

## Electrical Characteristics T<sub>J</sub> = 25 °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 1 mA, V <sub>GS</sub> = 0 V	25			V
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	I <sub>D</sub> = 10 mA, referenced to 25 °C		19		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0 V			500	μΑ
I <sub>GSS</sub>	Gate to Source Leakage Current, Forward	V <sub>GS</sub> = 20 V, V <sub>DS</sub> = 0 V			100	nA

### On Characteristics (Note 2)

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 1 \text{ mA}$	1.2	1.7	3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I <sub>D</sub> = 10 mA, referenced to 25 °C		-5		mV/°C
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 23 A		2.4	2.9	
r <sub>DS(on)</sub>	r <sub>DS(on)</sub> Static Drain to Source On Resistance	$V_{GS} = 4.5 \text{ V}, I_D = 18 \text{ A}$		3.4	4.2	mΩ
		$V_{GS} = 10 \text{ V}, I_D = 23 \text{ A}, T_J = 125 \text{ °C}$		3.5	4.3	
9 <sub>FS</sub>	Forward Transconductance	V <sub>DS</sub> = 5 V, I <sub>D</sub> = 23 A		159		S

### **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance	V 42.V.V. 0.V.	2090	2780	pF
Coss	Output Capacitance	$V_{DS} = 13 \text{ V}, V_{GS} = 0 \text{ V},$ $f = 1 \text{ MHz}$	577	770	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	1 - 1 1/11/12	128	195	pF
R <sub>a</sub>	Gate Resistance		1.1	2.4	Ω

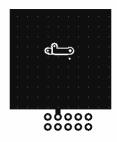
## **Switching Characteristics**

t <sub>d(on)</sub>	Turn-On Delay Time		10	20	ns
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 13 V, I <sub>D</sub> = 23 A,	4	10	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS}$ = 10 V, $R_{GEN}$ = 6 $\Omega$	27	43	ns
t <sub>f</sub>	Fall Time		3	10	ns
$Q_{q}$	Total Gate Charge	V <sub>GS</sub> = 0 V to 10 V	32	45	nC
$Q_q$	Total Gate Charge	$V_{GS} = 0 \text{ V to } 4.5 \text{ V}$ $V_{DD} = 13 \text{ V}$	15	21	nC
$Q_{gs}$	Gate to Source Gate Charge	I <sub>D</sub> = 23 A	6.3		nC
$Q_{gd}$	Gate to Drain "Miller" Charge		4.0		nC

### **Drain-Source Diode Characteristics**

V <sub>SD</sub> Source to	Source to Drain Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_{S} = 2 \text{ A}$ (Note 2)	0.48	0.8	V
	Source to Drain Diode Polward Voltage	$V_{GS} = 0 \text{ V}, I_{S} = 23 \text{ A}$ (Note 2)	0.79	1.2	\ \
t <sub>rr</sub>	Reverse Recovery Time	-I <sub>E</sub> = 23 A, di/dt = 300 A/ μs	23	36	ns
Q <sub>rr</sub>	Reverse Recovery Charge	T <sub>F</sub> = 23 A, di/dt = 300 A/ μs	17	31	nC

<sup>1</sup> R<sub>0JA</sub> is determined with the device mounted on a 1in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R<sub>0JC</sub> is guaranteed by design while R<sub>0CA</sub> is determined by the user's board design.



a. 50 °C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper.



b. 125 °C/W when mounted on a minimum pad of 2 oz copper.

- 2. Pulse Test: Pulse Width < 300  $\mu\text{s},$  Duty cycle < 2.0%.
- 3.  $E_{AS}$  of 84 mJ is based on starting  $T_J = 25$  °C, L = 1 mH,  $I_{AS} = 13$  A,  $V_{DD} = 23$  V,  $V_{GS} = 10$  V. 100% test at L = 0.3 mH,  $I_{AS} = 20$  A.
- 4. As an N-ch device, the negative Vgs rating is for low duty cycle pulse occurrence only. No continuous rating is implied.

## **Typical Characteristics** $T_J = 25$ °C unless otherwise noted

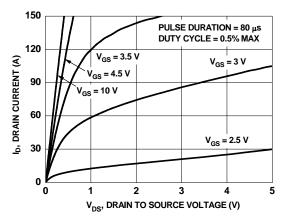


Figure 1. On Region Characteristics

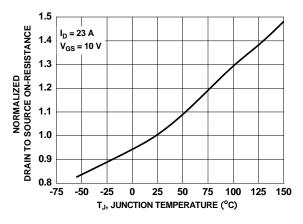


Figure 3. Normalized On Resistance vs Junction Temperature

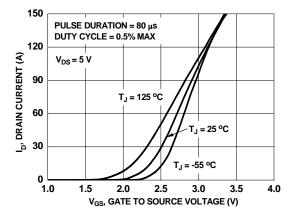


Figure 5. Transfer Characteristics

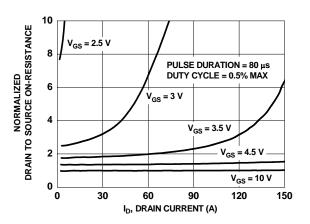


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

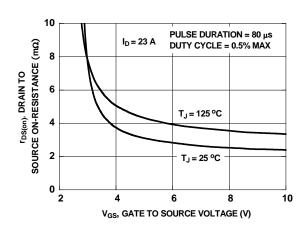


Figure 4. On-Resistance vs Gate to Source Voltage

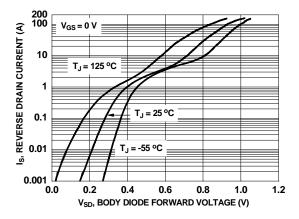


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

## **Typical Characteristics** $T_J = 25$ °C unless otherwise noted

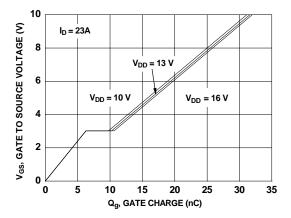


Figure 7. Gate Charge Characteristics

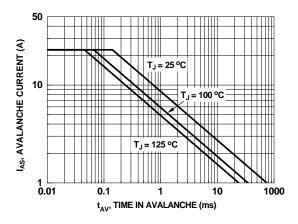


Figure 9. Unclamped Inductive Switching Capability

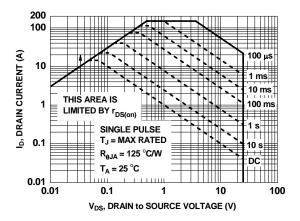


Figure 11. Forward Bias Safe Operating Area

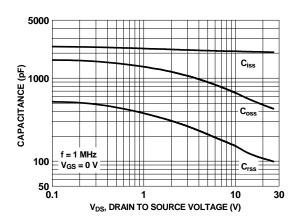


Figure 8. Capacitance vs Drain to Source Voltage

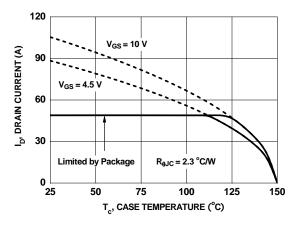


Figure 10. Maximum Continuous Drain Current vs Case Temperature

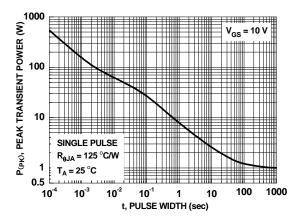


Figure 12. Single Pulse Maximum Power Dissipation

## Typical Characteristics T<sub>J</sub> = 25 °C unless otherwise noted

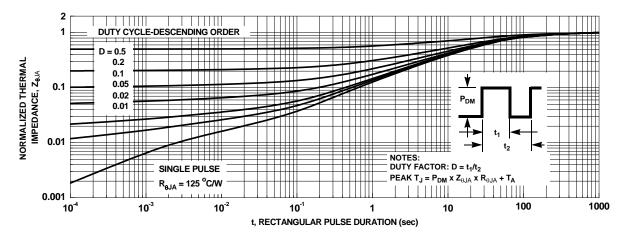


Figure 13. Junction-to-Ambient Transient Thermal Response Curve

## Typical Characteristics (continued)

## SyncFET Schottky body diode Characteristics

Fairchild's SyncFET process embeds a Schottky diode in parallel with PowerTrench MoSFET. This diode exhibits similar characteristics to a discrete external Schottky diode in parallel with a MOSFET. Figure 14 shows the reverses recovery characteristic of the FDMS7572S.

Schottky barrier diodes exhibit significant leakage at high temperature and high reverse voltage. This will increase the power in the device.

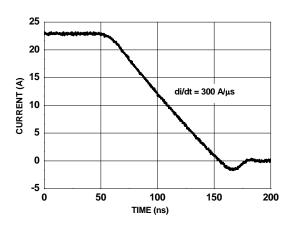


Figure 14. FDMS7572S SyncFET body diode reverse recovery characteristic

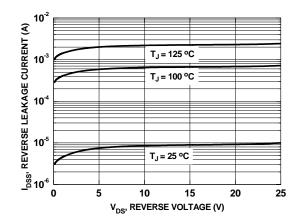
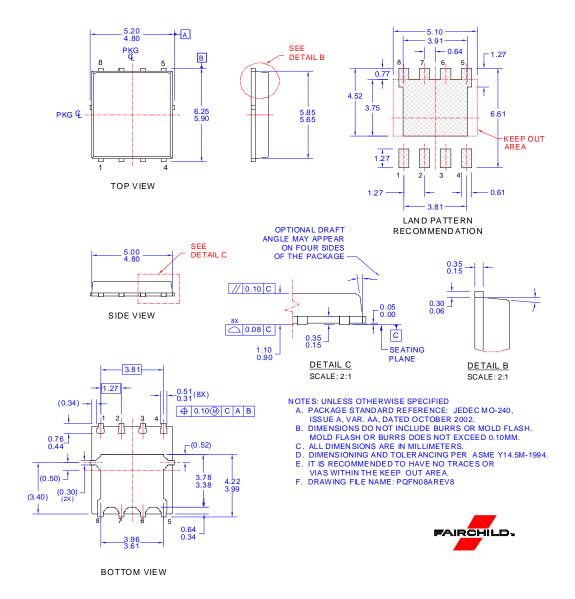


Figure 15. SyncFET body diode reverses leakage versus drain-source voltage

## **Dimensional Outline and Pad Layout**



Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings: https://www.fairchildsemi.com/evaluate/package-specifications/packageDetails.html?id=PN\_PQOAM-008





#### **TRADEMARKS**

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

AccuPower<sup>TM</sup>
Awinda<sup>®</sup>
AX-CAP<sup>®</sup>\*
BitSiC<sup>TM</sup>
Build it Now<sup>TM</sup>
CorePLUS<sup>TM</sup>
CorePOWER<sup>TM</sup>

CROSSVOLT™
CTL™
Current Transfer Logic™
DEUXPEED®

Dual Cool™ EcoSPARK® EfficentMax™ ESBC™

Fairchild<sup>®</sup>
Fairchild Semiconductor<sup>®</sup>
FACT Quiet Series<sup>™</sup>
FACT<sup>®</sup>
FAST<sup>®</sup>
FastvCore<sup>™</sup>
FETBench<sup>™</sup>

F-PFS™ FRFET®

Global Power Resource<sup>SM</sup> GreenBridge<sup>™</sup> Green FPS<sup>™</sup> Green FPS<sup>™</sup> e-Series<sup>™</sup>

Gmax<sup>™</sup> GTO<sup>™</sup> IntelliMAX<sup>™</sup> ISOPLANAR<sup>™</sup>

Marking Small Speakers Sound Louder and Better™

MegaBuck™
MICROCOUPLER™
MicroFET™
MicroPak™
MicroPak2™
MillerDrive™
MotionMax™

MotionGrid<sup>®</sup>
MTi<sup>®</sup>
MTx<sup>®</sup>
MVN<sup>®</sup>
mWSaver<sup>®</sup>
OptoHiT<sup>TM</sup>

®
PowerTrench®
PowerXS™

Programmable Active Droop™

QFET® QS™ Quiet Series™ RapidConfigure™

> Saving our world, 1mW/W/kW at a time™ SignalWise™ SmartMax™

SMART START™

Solutions for Your Success™ SPM®

STEALTH™
SUPERSOT™-3
SUPERSOT™-6
SUPERSOT™-8
SUPERSOT™-8
SUPERSOT™-8
SUPERSOT™-8
SUPERSOT™-8
SUPERSOT™-8
SUPERSOT™-8
SYNC-LOCK™

SYSTEM ®\*
GENERAL
TinyBoost®
TinyBuck®
TinyCalc™
TinyLogic®
TiNYOPTO™
TinyPower™
TinyPower™
TinyPWMT™
TinyWireT™
TranSiCT™
TriFault Detect™
TRUECURRENT®\*

SerDes\*
UHC®
UHtra FRFET™
UniFET™
VCX™
VisualMax™
VoltagePlus™
XS™
XS™
Xsens™
仙童™

μSerDes™

\*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

### DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. TO OBTAIN THE LATEST, MOST UP-TO-DATE DATASHEET AND PRODUCT INFORMATION, VISIT OUR WEBSITE AT <a href="http://www.fairchildsemi.com">http://www.fairchildsemi.com</a>. Fairchild does not assume any Liability Arising out of the application or use of any product or circuit described Herein; Neither does it convey any License under its patent rights, nor the rights of others. These specifications do not expand the terms of fairchild's worldwide terms and conditions, specifically the warranty therein. Which covers these products.

### LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used here in:

- Life support devices or systems are devices or systems which, (a) are
  intended for surgical implant into the body or (b) support or sustain life,
  and (c) whose failure to perform when properly used in accordance with
  instructions for use provided in the labeling, can be reasonably
  expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

### **ANTI-COUNTERFEITING POLICY**

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

### PRODUCT STATUS DEFINITIONS

### **Definition of Terms**

Datasheet Identification Product Status		Definition
Advance Information Formative / In Design		Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary First Production		Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed Full Production Datasheet contains final specifications. Fair make changes at any time without notice to		Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. 171







### TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

 $\begin{array}{lll} \mathsf{AccuPower^{\mathsf{TM}}} & \mathsf{F-PFS^{\mathsf{TM}}} \\ \mathsf{AttitudeEngine^{\mathsf{TM}}} & \mathsf{FRFET}^{\texttt{®}} \end{array}$ 

Awinda<sup>®</sup> Global Power Resource SM

AX-CAP®\* GreenBridge™
BitSiC™ Green FPS™
Build it Now™ Green FPS™ e-Series™

Current Transfer Logic™ Making Small Speakers Sound Louder

DEUXPEED® and Better™

Dual Cool™ MegaBuck™

EcoSPARK® MICROCOUPLER™

EfficientMax™ MicroFET™

EfficientMax™ MicroFET™
ESBC™ MicroPak™
MicroPak™
MicroPak2™
Fairchild® MillerDrive™
MotionMax™
Fairchild Semiconductor®

Farchild Semiconductor

FACT Quiet Series™
FACT®

FastvCore™
FETBench™
FPS™

MotionGrid®
MTI®
MTX®
MVN®
FETBench™
MVN®
FPS™

OptoHiT™
OPTOLOGIC®

OPTOPLANAR®

Power Supply WebDesigner™ PowerTrench®

PowerXS™

Programmable Active Droop™ OFFT®

QS™ Quiet Series™ RapidConfigure™

TM TM

Saving our world, 1mW/W/kW at a time™

SignalWise™ SmartMax™ SMART START™

Solutions for Your Success™

SPM®
STEALTH™
SuperFET®
SuperSOT™-3
SuperSOT™-6
SuperSOT™-8
SupreMOS®
SyncFET™
Sync-Lock™

SYSTEM GENERAL®'
TinyBoost®
TinyBuck®
TinyCalc™
TinyLogic®
TINYOPTO™
TinyPower™
TinyPWM™
TinyPWM™
TranSiC™
TriFault Detect™
TRUECURRENT®\*\*
uSerDes™

SerDes"
UHC<sup>®</sup>
Ultra FRFET™
UniFET™
VCX™
VisualMax™
VoltagePlus™
XS™
XS™
XS™

仙童®

\* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

#### DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. TO OBTAIN THE LATEST, MOST UP-TO-DATE DATASHEET AND PRODUCT INFORMATION, VISIT OUR WEBSITE AT <a href="http://www.fairchildsemi.com">http://www.fairchildsemi.com</a>, FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

### AUTHORIZED USE

Unless otherwise specified in this data sheet, this product is a standard commercial product and is not intended for use in applications that require extraordinary levels of quality and reliability. This product may not be used in the following applications, unless specifically approved in writing by a Fairchild officer: (1) automotive or other transportation, (2) military/aerospace, (3) any safety critical application – including life critical medical equipment – where the failure of the Fairchild product reasonably would be expected to result in personal injury, death or property damage. Customer's use of this product is subject to agreement of this Authorized Use policy. In the event of an unauthorized use of Fairchild's product, Fairchild accepts no liability in the event of product failure. In other respects, this product shall be subject to Fairchild's Worldwide Terms and Conditions of Sale, unless a separate agreement has been signed by both Parties.

### **ANTI-COUNTERFEITING POLICY**

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Terms of Use

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

### PRODUCT STATUS DEFINITIONS

### **Definition of Terms**

Deminition of Terms		
Datasheet Identification		Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. 177

## **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

FDMS7572S